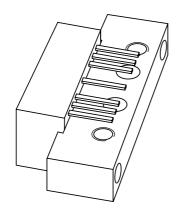
## **DISCRETE SEMICONDUCTORS**

# DATA SHEET



## **BGY587B** 550 MHz, 27 dB gain push-pull amplifier

Product specification Supersedes data of 1997 Apr 10 2001 Oct 22





**Philips Semiconductors** 

## 550 MHz, 27 dB gain push-pull amplifier

#### **BGY587B**

#### **FEATURES**

- · Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

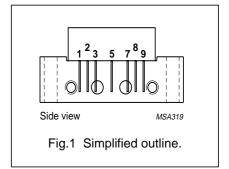
#### **DESCRIPTION**

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of +24 V (DC).

#### **PINNING - SOT115J**

PIN	DESCRIPTION	
1	input	
2	common	
3	common	
5	+V <sub>B</sub>	
7	common	
8	common	
9	output	

#### **PIN CONFIGURATION**



#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	26.2	27.8	dB
		f = 550 MHz	27.5	_	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = +24 V	_	340	mA

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	55	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C
V <sub>B</sub>	DC supply voltage	_	+28	V

## 550 MHz, 27 dB gain push-pull amplifier

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#### **CHARACTERISTICS**

**Table 1** Bandwidth 40 to 550 MHz;  $T_{case} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	26.2	27.8	dB
		f = 550 MHz	27.5		dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.5	2.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz	_	±0.4	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 550 MHz	18	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 550 MHz	18	_	dB
СТВ	composite triple beat	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	_	<i>–</i> 57	dB
X <sub>mod</sub>	cross modulation	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	-60	dB
CSO	composite second order distortion	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz	_	-57	dB
d <sub>2</sub>	second order distortion	note 1	_	-68	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	61	_	dBmV
F	noise figure	f = 550 MHz	_	6.5	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3	_	340	mA

#### Notes

```
 \begin{array}{ll} \text{1.} & f_p = 55.25 \text{ MHz; V}_p = 44 \text{ dBmV;} \\ & f_q = 493.25 \text{ MHz; V}_q = 44 \text{ dBmV;} \\ & \text{measured at f}_p + f_q = 548.5 \text{ MHz.} \\ \end{array}
```

2. Measured according to DIN45004B;

```
f_p = 540.25 \text{ MHz}; V_p = V_o = 66.5 \text{ dBmV};
```

 $f_q = 547.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$ 

 $f_r = 549.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$ 

measured at  $f_p + f_q - f_r = 538.25$  MHz.

3. The module normally operates at  $V_B$  = +24 V, but is able to withstand supply transients up to +30 V.

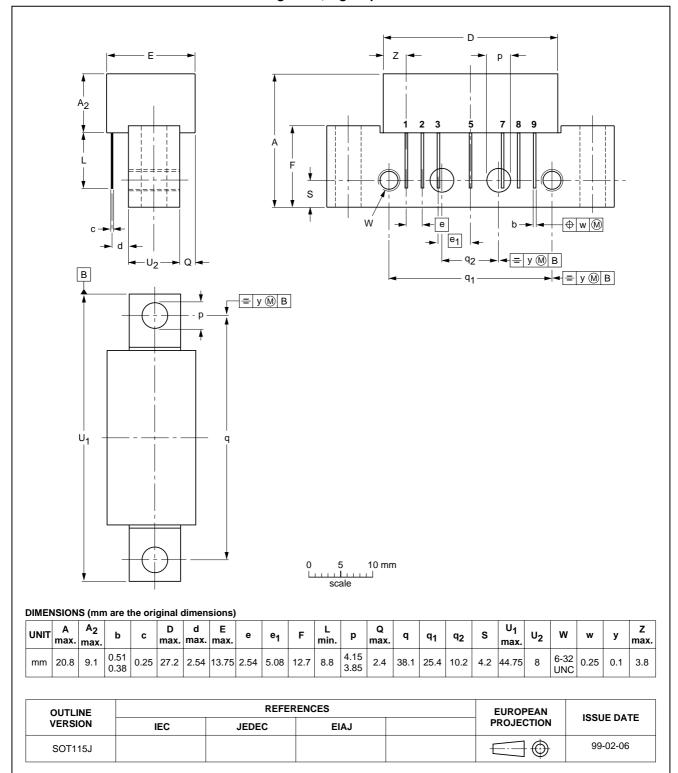
## 550 MHz, 27 dB gain push-pull amplifier

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#### **PACKAGE OUTLINE**

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

SOT115J



### 550 MHz, 27 dB gain push-pull amplifier

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#### **DATA SHEET STATUS**

DATA SHEET STATUS(1)	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
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NOTES

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NOTES

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